NSN 5962-01-101-3099



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-101-3099 **Body Length:** Between 0.895 inches and 0.905 inches **Body Width:** Between 0.245 inches and 0.255 inches **Body Height:** Between 0.130 inches and 0.140 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and positive outputs and low power and high speed and 3-state output **Inclosure Material: Plastic Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

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Demilitarization: Yes - demil/mli